PRODUCT SPECIFICATION



Integrated Circuits Group

LH28F128BFHED-PWTLZ8 Flash Memory 128Mbit (8Mbitx16)

(Model Number: LHF12FZ8)

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To;	
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Product Type <u>128 M</u>	lbit Flash Memory
L H 2 8 F I 2 8	BBFHED—PWTLZ8
Model No(L H F 1 2 F Z 8)
If you have any objections, pleas	se contact us before issuing purchasing order.
* This specifications contains 40	pages including the cover and appendix.
* Refer to LH28F128BF Series	Appendix (FUM00701).
CUSTOMERS ACCEPTANCE	
DATE:	
BY:	PRESENTED
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	$\frac{BY:}{X} \frac{1}{10} $
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Integrated Circuits Group SHARP CORPORATION

LHF12FZ8

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 - The products covered herein are designed and manufactured for the following application areas. When using the products covered herein for the equipment listed in Paragraph (2), even for the following application areas, be sure to observe the precautions given in Paragraph (2). Never use the products for the equipment listed in Paragraph (3).
 - Office electronics
 - Instrumentation and measuring equipment
 - Machine tools
 - Audiovisual equipment
 - Home appliance
 - Communication equipment other than for trunk lines
 - (2) Those contemplating using the products covered herein for the following equipment <u>which demands high</u> <u>reliability</u>, should first contact a sales representative of the company and then accept responsibility for incorporating into the design fail-safe operation, redundancy, and other appropriate measures for ensuring reliability and safety of the equipment and the overall system.
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 - Mainframe computers
 - Traffic control systems
 - Gas leak detectors and automatic cutoff devices
 - Rescue and security equipment
 - Other safety devices and safety equipment, etc.
 - (3) Do not use the products covered herein for the following equipment which demands extremely high performance in terms of functionality, reliability, or accuracy.
 - Aerospace equipment
 - Communications equipment for trunk lines
 - Control equipment for the nuclear power industry
 - Medical equipment related to life support, etc.
 - (4) Please direct all queries and comments regarding the interpretation of the above three Paragraphs to a sales representative of the company.
 - Please direct all queries regarding the products covered herein to a sales representative of the company.



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LHF12FZ8



LH28F128BFHED-PWTLZ8 128Mbit (8Mbit×16) Page Mode Dual Work Flash MEMORY

- 128M density with 16Bit I/O Interface
 2 Bank Enable (BE₀#, BE₁#) Control
- High Performance Reads
 90/35ns 8-Word Page Mode
- Configurative 8-Plane Dual Work
 - Flexible Partitioning
 - Read operations during Block Erase or (Page Buffer) Program
 - Status Register for Each Partition

Low Power Operation

- 2.7V Read and Write Operations
- Automatic Power Savings Mode Reduces I_{CCR} in Static Mode
- Enhanced Code + Data Storage
 5µs Typical Erase/Program Suspends
- OTP (One Time Program) Block
 - 4-Word Factory-Programmed Area
 - 4-Word User-Programmable Area
- High Performance Program with Page Buffer
 - 16-Word Page Buffer
 - + 5µs/Word (Typ.) at 12V V_{PP}
- Operating Temperature -40°C to +85°C
- CMOS Process (P-type silicon substrate)

- Flexible Blocking Architecture
 - Sixteen 4K-word Parameter Blocks
 - Two-hundred and fifty-four 32K-word Main Blocks
 - Top and Bottom Parameter Location
- Enhanced Data Protection Features
 - Individual Block Lock and Block Lock-Down with Zero-Latency
 - All blocks are locked at power-up or device reset.
 - Absolute Protection with $V_{PP} \leq V_{PPLK}$
 - Block Erase, Bank Erase, (Page Buffer) Word Program Lockout during Power Transitions
- Automated Erase/Program Algorithms
 - 3.0V Low-Power 11µs/Word (Typ.) Programming
 - 12V No Glue Logic 9µs/Word (Typ.) Production Programming and 0.5s Erase (Typ.)
- Cross-Compatible Command Support
 - Basic Command Set
 - Common Flash Interface (CFI)
- Extended Cycling Capability
 - Minimum 100,000 Block Erase Cycles
- 48-Lead TSOP
- ETOX^{TM*} Flash Technology
- Not designed or rated as radiation hardened

The product, which is 8-Plane Page Mode Dual Work (Simultaneous Read while Erase/Program) Flash memory, is a low power, high density, low cost, nonvolatile read/write storage solution for a wide range of applications. The product can operate at V_{CC} =2.7V-3.6V and V_{PP} =1.65V-3.6V or 11.7V-12.3V. Its low voltage operation capability greatly extends battery life for portable applications.

The product provides high performance asynchronous page mode. It allows code execution directly from Flash, thus eliminating time consuming wait states. Furthermore, its newly configurative partitioning architecture allows flexible dual work operation.

The memory array block architecture utilizes Enhanced Data Protection features, and provides separate Parameter and Main Blocks that provide maximum flexibility for safe nonvolatile code and data storage.

Fast program capability is provided through the use of high speed Page Buffer Program.

Special OTP (One Time Program) block provides an area to store permanent code such as a unique number.

* ETOX is a trademark of Intel Corporation.

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Figure 1. 48-Lead TSOP (Normal Bend) Pinout

		Table 1. Pin Descriptions			
Symbol	Туре	Name and Function			
A ₀ -A ₂₁	INPUT	ADDRESS INPUTS: Inputs for addresses. A ₀ -A ₂₁			
DQ ₀ -DQ ₁₅	INPUT/ OUTPUT	DATA INPUTS/OUTPUTS: Inputs data and commands during CUI (Command User Interface) write cycles, outputs data during memory array, status register, query code, identifier code and partition configuration register code reads. Data pins float to high-impedance (High Z) when the chip or outputs are deselected. Data is internally latched during an erase or program cycle.			
BE ₀ #, BE ₁ #	INPUT	BANK ENABLE: Activates the device's control logic, input buffers, decoders and sense amplifiers. BE_0 #-high (V_{IH}) and BE_1 #-high (V_{IH}) deselects the device and reduces power consumption to standby levels.			
RST#	INPUT	RESET: When low (V_{IL}), RST# resets internal automation and inhibits write operations which provides data protection. RST#-high (V_{IH}) enables normal operation. After power-up or reset mode, the device is automatically set to read array mode. RST# must be low during power-up/down.			
OE#	INPUT	OUTPUT ENABLE: Gates the device's outputs during a read cycle.			
WE#	INPUT	WRITE ENABLE: Controls writes to the CUI and array blocks. Addresses and data are latched on the rising edge of $BE_0^{\#}$ or $BE_1^{\#}$ or WE# (whichever goes high first).			
WP#	INPUT	WRITE PROTECT: When WP# is V_{IL} , locked-down blocks cannot be unlocked. Erase or program operation can be executed to the blocks which are not locked and not locked-down. When WP# is V_{IH} , lock-down is disabled.			
V _{PP}	INPUT	MONITORING POWER SUPPLY VOLTAGE: V_{PP} is not used for power supply pin.With $V_{PP} \leq V_{PPLK}$, block erase, bank erase, (page buffer) program or OTP program cannot be executed and should not be attempted.Applying $12V\pm0.3V$ to V_{PP} provides fast erasing or fast programming mode. In this mode, V_{PP} is power supply pin. Applying $12V\pm0.3V$ to V_{PP} during erase/program can only be done for a maximum of 1,000 cycles on each block. V_{PP} may be connected to 			
V _{CC}	SUPPLY	DEVICE POWER SUPPLY (2.7V-3.6V): With $V_{CC} \leq V_{LKO}$, all write attempts to the flash memory are inhibited. Device operations at invalid V_{CC} voltage (see DC Characteristics) produce spurious results and should not be attempted.			
GND	SUPPLY	GROUND: Do not float any ground pins.			

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				1				2			
	THEN THE MODES ALLOWED IN THE OTHER PARTITION IS:										
IF ONE PARTITION IS:	Read Array	Read ID/OTP	Read Status	Read Query	Word Program	Page Buffer Program	OTP Program	Block Erase	Bank Erase	Program Suspend	Hrase
Read Array	Х	X	Х	Х	Х	Х		Х		X	X
Read ID/OTP	Х	X	Х	Х	Х	Х		Х		X	X
Read Status	Х	X	Х	Х	Х	Х	X	Х	Х	X	X
Read Query	Х	X	Х	Х	Х	Х		Х		X	X
Word Program	Х	X	Х	Х							X
Page Buffer Program	Х	X	Х	X							X
OTP Program			Х								
Block Erase	Х	X	Х	Х							
Bank Erase			Х								
Program Suspend	Х	X	Х	X							Х
Block Erase Suspend	Х	X	Х	Х	Х	Х				X	

Table 2. Simultaneous Operation Modes Allowed with Eight $Planes^{(1, 2)}$

NOTES:

1. "X" denotes the operation available.

2. Configurative Partition Dual Work Restrictions:

Status register reflects partition state, not WSM (Write State Machine) state - this allows a status register for each partition. Only one partition can be erased or programmed at a time - no command queuing. Commands must be written to an address within the block targeted by that command.

	BLO	CK NUMBER	ADDRESS RANGE
	134	4K-WORD	3FF000H - 3FFFFFH
	133	4K-WORD	3FE000H - 3FEFFFH
	132	4K-WORD	3FD000H - 3FDFFFH
	131	4K-WORD	3FC000H - 3FCFFFH 3FB000H - 3FBFFFH
	130 129	4K-WORD 4K-WORD	3FA000H - 3FAFFFH
	129	4K-WORD	3F9000H - 3F9FFFH
	127	4K-WORD	3F8000H - 3F8FFFH
	126	32K-WORD	3F0000H - 3F7FFFH
_	125	32K-WORD	3E8000H - 3EFFFFH
PLANE3 (PARAMETER PLANE)	124	32K-WORD	3E0000H - 3E7FFFH 3D8000H - 3DFFFFH
Z	123 122	32K-WORD 32K-WORD	3D0000H - 3D7FFFH
Γ	121	32K-WORD	3C8000H - 3CFFFFH
Р	120	32K-WORD	3C0000H - 3C7FFFH
Η̈́	119	32K-WORD	3B8000H - 3BFFFFH
E	118	32K-WORD	3B0000H - 3B7FFFH
Ŧ	117	32K-WORD 32K-WORD	3A8000H - 3AFFFFH 3A0000H - 3A7FFFH
Ā	115	32K-WORD	398000H - 39FFFFH
R	114	32K-WORD	390000H - 397FFFH
ΡA	113	32K-WORD	388000H - 38FFFFH
0	112	32K-WORD	380000H - 387FFFH
Ш	111	32K-WORD	378000H - 37FFFFH
Z	110 109	32K-WORD 32K-WORD	370000H - 377FFFH 368000H - 36FFFFH
L∧	109	32K-WORD	360000H - 367FFFH
Р	107	32K-WORD	358000H - 35FFFFH
	106	32K-WORD	350000H - 357FFFH
	105	32K-WORD	348000H - 34FFFFH
	104	32K-WORD	340000H - 347FFFH
	103 102	32K-WORD 32K-WORD	_ 338000H - 33FFFFH 330000H - 337FFFH
	102	32K-WORD	328000H - 32FFFFH
	100	32K-WORD	320000H - 327FFFH
	99	32K-WORD	318000H - 31FFFFH
	98	32K-WORD	_310000H - 317FFFH
	<u>97</u> 96	32K-WORD 32K-WORD	308000H - 30FFFFH 300000H - 307FFFH
	90	J2K-WORD	_300000H - 30/111H
	95	32K-WORD	2F8000H - 2FFFFFH
	94	32K-WORD	2F0000H - 2F7FFFH
	93	32K-WORD	2E8000H - 2EFFFFH 2E0000H - 2E7FFFH
	92 91	32K-WORD 32K-WORD	2D8000H - 2DFFFFH
	90	32K-WORD	2D0000H - 2D7FFFH
	89	32K-WORD	2C8000H - 2CFFFFH
	88	32K-WORD	2C0000H - 2C7FFFH
\sim	87	32K-WORD	2B8000H - 2BFFFFH
Ê	86	32K-WORD	2B0000H - 2B7FFFH 2A8000H - 2AFFFFH
F	85 84	32K-WORD 32K-WORD	2A0000H - 2A7FFFH
Ľ,	83	32K-WORD	298000H - 29FFFFH
IF	82	32K-WORD	290000H - 297FFFH
1	81	32K-WORD	288000H - 28FFFFH
ō	80	32K-WORD	280000H - 287FFFH
H	79	32K-WORD	278000H - 27FFFFH
Z	78	32K-WORD	270000H - 277FFFH 268000H - 26FFFFH
PLANE2 (UNIFORM PLANI	77 76	32K-WORD 32K-WORD	260000H - 267FFFH
	75	32K-WORD	258000H - 25FFFFH
ΙĒ	74	32K-WORD	250000H - 257FFFH
4	73	32K-WORD	248000H - 24FFFFH
Ы	72	32K-WORD	240000H - 247FFFH
	71	32K-WORD	_ 238000H - 23FFFFH 230000H 237EEEH
	70 69	32K-WORD 32K-WORD	230000H - 237FFFH 228000H - 22FFFFH
	68	32K-WORD	220000H - 227FFFH
	67	32K-WORD	218000H - 21FFFFH
	67 66	32K-WORD 32K-WORD	210000H - 217FFFH

BLOCK NUMBER ADDRESS RANGE

	BLC	OCK NUMBER	ADDRESS RAN
	63	32K-WORD	1F8000H - 1FFFFFH
	62	32K-WORD	1F0000H - 1F7FFFH
	61	32K-WORD	1E8000H - 1EFFFFH
	60	32K-WORD	1E0000H - 1E7FFFH
	59	32K-WORD	1D8000H - 1DFFFFH 1D0000H - 1D7FFFH
	58 57	32K-WORD	1C8000H - 1CFFFFH
	56	32K-WORD 32K-WORD	1C0000H - 1C7FFFH
_	55	32K-WORD	1B8000H - 1BFFFFH
Ξ	54	32K-WORD	1B0000H - 1B7FFFH
PLANE1 (UNIFORM PLANE	53	32K-WORD	1A8000H - 1AFFFFH
L A	52	32K-WORD	1A0000H - 1A7FFFH
Ы	51	32K-WORD	198000H - 19FFFFH
Σ	50	32K-WORD	190000H - 197FFFH
R	49	32K-WORD	188000H - 18FFFFH
C IT	48	32K-WORD	180000H - 187FFFH
Ę	47	32K-WORD	178000H - 17FFFFH 170000H - 177FFFH
5	46	32K-WORD 32K-WORD	168000H - 16FFFH
	43	32K-WORD	160000H - 167FFFH
Ξ	43	32K-WORD	158000H - 15FFFFH
Z	42	32K-WORD	150000H - 157FFFH
Ą	41	32K-WORD	148000H - 14FFFFH
Ы	40	32K-WORD	140000H - 147FFFH
	39	32K-WORD	138000H - 13FFFFH
	38	32K-WORD	130000H - 137FFFH
	37	32K-WORD	128000H - 12FFFFH
	36	32K-WORD	120000H - 127FFFH
	35	32K-WORD	118000H - 11FFFFH
	34	32K-WORD 32K-WORD	110000H - 117FFFH 108000H - 10FFFFH
	32	32K-WORD	100000H - 107FFFH
	02	32R 110RD	
	31	32K-WORD	0F8000H - 0FFFFFH
	30	32K-WORD	0F0000H - 0F7FFFH
	29	32K-WORD	0E8000H - 0EFFFFH
	28	32K-WORD	0E0000H - 0E7FFFH
	27	32K-WORD	0D8000H - 0DFFFFH
	26	32K-WORD 32K-WORD	0D0000H - 0D7FFFH 0C8000H - 0CFFFFH
	25 24	32K-WORD	0C0000H - 0C7FFFH
	24	32K-WORD	0B8000H - 0BFFFFH
m	22	32K-WORD	0B0000H - 0B7FFFH
Ē	21	32K-WORD	0A8000H - 0AFFFFH
FORM PLANE	20	32K-WORD	0A0000H - 0A7FFFH
Ы	19	32K-WORD	098000H - 09FFFFH
$\overline{\mathbf{v}}$	18	32K-WORD	090000H - 097FFFH
2	17	32K-WORD	088000H - 08FFFFH
ō	16	32K-WORD	080000H - 087FFFH
H	15	32K-WORD	078000H - 07FFFFH
Z	14	32K-WORD	070000H - 077FFFH 068000H - 06FFFFH
E)	13 12	32K-WORD 32K-WORD	060000H - 067FFFH
<u>S</u>	11	32K-WORD	058000H - 05FFFFH
モ	10	32K-WORD	050000H - 057FFFH
PLANE0	9	32K-WORD	048000H - 04FFFFH
Ľ.	8	32K-WORD	040000H - 047FFFH
	7	32K-WORD	038000H - 03FFFFH
	6	32K-WORD	030000H - 037FFFH
	5	32K-WORD	028000H - 02FFFFH
	4	32K-WORD	020000H - 027FFFH
	3	32K-WORD	018000H - 01FFFFH
	2	32K-WORD	010000H - 017FFFH 008000H - 00FFFFH
	1 0	32K-WORD 32K-WORD	000000H - 007FFFH
	10	52K- WOKD	

Figure 2.1. Memory Map (Top Parameter)

BLOCK NUMBER ADDRESS RANGE

134 32K-WORD 3F8000H 3FFFFH 133 32K-WORD 3F8000H 3E7FFFH 131 32K-WORD 3E8000H 3E7FFFH 130 32K-WORD 3E8000H 3DFFFH 129 32K-WORD 3D8000H 3DFFFFH 129 32K-WORD 3C8000H 3DFFFFH 126 32K-WORD 3C8000H 3DFFFFH 126 32K-WORD 3B8000H 3DFFFFH 123 32K-WORD 3A8000H 3AFFFFH 124 32K-WORD 3A8000H 3AFFFFH 122 32K-WORD 388000H 3AFFFFH 120 32K-WORD 38000H 3AFFFFH 116 32K-WORD 368000H 3AFFFFH 116 32K-WORD 368000H 3AFFFFH 117 32K-WORD 368000H 3AFFFFH 118 32K-WORD 360000H 3AFFFFH 114 32K-WORD 38000H 3AFFFFH 112 32K-WORD 328000H<		DL	JCK NUMBER	ADDRESS KAN
I32 32K-WORD 3E8000H - 3E7FFFH I30 32K-WORD 3E0000H - 3D7FFFH I29 32K-WORD 3D0000H - 3D7FFFH I28 32K-WORD 3C0000H - 3C7FFFH I26 32K-WORD 3C0000H - 3D7FFFH I27 32K-WORD 3B8000H - 3BFFFFH I26 32K-WORD 3A8000H - 3AFFFFH I27 32K-WORD 3A8000H - 3FFFFH I24 32K-WORD 3A8000H - 3FFFFH I24 32K-WORD 38000H - 3FFFFH I22 32K-WORD 38000H - 3FFFFH I21 32K-WORD 38000H - 3FFFFH I16 32K-WORD 38000H - 3FFFFH I17 32K-WORD 358000H - 3FFFFH I18 32K-WORD 350000H - 3FFFFH I13 32K-WORD 340000H - 34FFFFH I14 32K-WORD 320000H - 32FFFFH I12 32K-WORD 320000H - 31FFFFH I06 32K-WORD 320000H - 31FFFFH I07 32K-WORD 300000H - 307FFFH I06		134	32K-WORD	3F8000H - 3FFFFFH
I32 32K-WORD 3E8000H - 3E7FFFH I30 32K-WORD 3E0000H - 3D7FFFH I29 32K-WORD 3D0000H - 3D7FFFH I28 32K-WORD 3C0000H - 3C7FFFH I26 32K-WORD 3C0000H - 3D7FFFH I27 32K-WORD 3B8000H - 3BFFFFH I26 32K-WORD 3A8000H - 3AFFFFH I27 32K-WORD 3A8000H - 3FFFFH I24 32K-WORD 3A8000H - 3FFFFH I24 32K-WORD 38000H - 3FFFFH I22 32K-WORD 38000H - 3FFFFH I21 32K-WORD 38000H - 3FFFFH I16 32K-WORD 38000H - 3FFFFH I17 32K-WORD 358000H - 3FFFFH I18 32K-WORD 350000H - 3FFFFH I13 32K-WORD 340000H - 34FFFFH I14 32K-WORD 320000H - 32FFFFH I12 32K-WORD 320000H - 31FFFFH I06 32K-WORD 320000H - 31FFFFH I07 32K-WORD 300000H - 307FFFH I06		133		3F0000H - 3F7FFFH
I31 32K-WORD 3E0000H - 3E7FFH 130 32K-WORD 3D8000H - 3D7FFFH 128 32K-WORD 3C8000H - 3CFFFFH 128 32K-WORD 3C8000H - 3CFFFFH 126 32K-WORD 3B0000H - 3FFFFH 126 32K-WORD 3B0000H - 3FFFFH 123 32K-WORD 3A0000H - 3FFFFH 124 32K-WORD 38000H - 3FFFFH 123 32K-WORD 38000H - 3FFFFH 123 32K-WORD 38000H - 3FFFFH 120 32K-WORD 38000H - 3FFFFH 120 32K-WORD 38000H - 3FFFFH 117 32K-WORD 36000H - 3FFFFH 118 32K-WORD 36000H - 3FFFFH 113 32K-WORD 350000H - 3FFFFH 113 32K-WORD 350000H - 3FFFFH 113 32K-WORD 350000H - 3FFFFH 113 32K-WORD 328000H - 3FFFFH 113 32K-WORD 328000H - 3FFFFH 110 32K-WORD 328000H - 3FFFFH 111 32K-WO				
I30 32K-WORD 3D8000H 3DFFFH 129 32K-WORD 3D0000H 3D7FFFH 127 32K-WORD 3C8000H 3CFFFFH 127 32K-WORD 3B000H 3BFFFFH 126 32K-WORD 3B000H 3BFFFFH 125 32K-WORD 3A8000H 3FFFFH 121 32K-WORD 388000H 3FFFFH 122 32K-WORD 388000H 3FFFFH 121 32K-WORD 388000H 3FFFFH 121 32K-WORD 378000H 3FFFFH 118 32K-WORD 368000H 3FFFFH 117 32K-WORD 358000H 3FFFFH 116 32K-WORD 350000H 3FFFFH 113 32K-WORD 350000H 3FFFFH 113 32K-WORD 328000H 32FFFFH 111 32K-WORD 328000H 32FFFFH 106 32K-WORD 328000H 32FFFFH 107 32K-WORD 328000H				
I29 32K-WORD 3D0000H 3D7FFFH I28 32K-WORD 3C8000H 3CFFFFH I27 32K-WORD 3B8000H 3BFFFFH I27 32K-WORD 3B8000H 3BFFFFH I24 32K-WORD 3A8000H 3AFFFFH I25 32K-WORD 3A0000H 3AFFFFH I24 32K-WORD 3A0000H 3FFFFH I22 32K-WORD 380000H 3FFFFH I21 32K-WORD 380000H 3FFFFH I20 32K-WORD 380000H 3FFFFH I16 32K-WORD 36000H 3FFFFH I17 32K-WORD 36000H 3FFFFH I13 32K-WORD 358000H 3FFFFH I13 32K-WORD 33000H 3FFFFH I10 32K-WORD 33000H 3FFFFH I113 32K-WORD 328000H 32FFFH I103 32K-WORD 328000H 32FFFH I06 32K-WORD 30000H				
I28 32K-WORD 3C8000H - 3CFFFFH I27 32K-WORD 3B8000H - 3BFFFFH I26 32K-WORD 3B8000H - 3B7FFFH I26 32K-WORD 3A0000H - 3A7FFFH I23 32K-WORD 3A0000H - 3A7FFFH I23 32K-WORD 3A0000H - 3A7FFFH I23 32K-WORD 380000H - 387FFFH I21 32K-WORD 380000H - 387FFFH I20 32K-WORD 380000H - 387FFFH I19 32K-WORD 380000H - 37FFFFH I16 32K-WORD 360000H - 37FFFFH I16 32K-WORD 360000H - 37FFFFH I17 32K-WORD 360000H - 37FFFFH I13 32K-WORD 340000H - 34FFFFH I10 32K-WORD 320000H - 327FFFH I10 32K-WORD 320000H - 327FFFH I03 32K-WORD 320000H - 327FFFH I04 32K-WORD 320000H - 327FFFH I05 32K-WORD 300000H - 307FFFH I04 32K-WORD 300000H - 2FFFFH I03<			32K-WORD	
IDENTIFY IDENTIFY IDENTIFY IDENTIFY IDENTIFY IDENTIFY IDE			32K-WORD	3D0000H - 3D7FFFH
IDENTIFY IDENTIFY IDENTIFY IDENTIFY IDENTIFY IDENTIFY IDE		128	32K-WORD	3C8000H - 3CFFFFH
IDE 126 32K-WORD 3B8000H - 3BFFFH 125 32K-WORD 3A8000H - 3B7FFFH 124 32K-WORD 3A0000H - 3A7FFFH 122 32K-WORD 3A0000H - 397FFFH 121 32K-WORD 38000H - 39FFFFH 121 32K-WORD 380000H - 39FFFFH 121 32K-WORD 380000H - 38FFFFH 120 32K-WORD 380000H - 37FFFFH 117 32K-WORD 376000H - 37FFFFH 118 32K-WORD 360000H - 36FFFFH 115 32K-WORD 356000H - 36FFFFH 113 32K-WORD 350000H - 37FFFH 113 32K-WORD 350000H - 37FFFH 113 32K-WORD 338000H - 34FFFFH 109 32K-WORD 338000H - 32FFFFH 106 32K-WORD 328000H - 32FFFFH 106 32K-WORD 300000H - 307FFFH 103 32K-WORD 308000H - 30FFFFH 103 32K-WORD 308000H - 2FFFFH 104 32K-WORD 308000H - 2FFFFH			32K-WORD	3C0000H - 3C7FFFH
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72 32K-WORD 208000H - 20FFFFH			32K-WORD	
		73	32K WORD	1210000H - 217FFFH
		15	J2K-WORD	
		72	32K-WORD	208000H - 20FFFFH

	BLC	OCK NUMBER	_ADDRESS RANGE
	70	32K-WORD	1F8000H - 1FFFFFH
	69	32K-WORD	1F0000H - 1F7FFFH 1E8000H - 1EFFFFH
	68 67	32K-WORD 32K-WORD	1E0000H - 1E7FFFH
	66	32K-WORD	1D8000H - 1DFFFFH
	65	32K-WORD	1D0000H - 1D7FFFH
	64	32K-WORD	1C8000H - 1CFFFFH
	63	32K-WORD	1C0000H - 1C7FFFH
田	62 61	32K-WORD 32K-WORD	1B8000H - 1BFFFFH 1B0000H - 1B7FFFH
PLANE1 (UNIFORM PLANE)	60	32K-WORD	1A8000H - 1AFFFFH
Ľ,	59	32K-WORD	1A0000H - 1A7FFFH
II	58	32K-WORD	198000H - 19FFFFH
2	57	32K-WORD	190000H - 197FFFH
õ	56 55	32K-WORD 32K-WORD	188000H - 18FFFFH 180000H - 187FFFH
H I	54	32K-WORD	178000H - 17FFFFH
5	53	32K-WORD	170000H - 177FFFH
U)	52	32K-WORD	168000H - 16FFFFH
E.	51	32K-WORD	160000H - 167FFFH
Z	50 49	32K-WORD	158000H - 15FFFFH 150000H - 157FFFH
LA	48	32K-WORD 32K-WORD	148000H - 14FFFFH
P	47	32K-WORD	140000H - 147FFFH
	46	32K-WORD	138000H - 13FFFFH
	45	32K-WORD	130000H - 137FFFH
	44 43	32K-WORD	128000H - 12FFFFH
	43	32K-WORD 32K-WORD	120000H - 127FFFH 118000H - 11FFFFH
	41	32K-WORD	110000H - 117FFFH
	40	32K-WORD	108000H - 10FFFFH
	39	32K-WORD	100000H - 107FFFH
	38 37	32K-WORD 32K-WORD	0F8000H - 0FFFFFH 0F0000H - 0F7FFFH
	36	32K-WORD	0E8000H - 0EFFFFH
	35	32K-WORD	0E0000H - 0E7FFFH
	34	32K-WORD	0D8000H - 0DFFFFH
	33 32	32K-WORD 32K-WORD	0D0000H - 0D7FFFH 0C8000H - 0CFFFFH
	31	32K-WORD	0C0000H - 0C7FFFH
	30	32K-WORD	0B8000H - 0BFFFFH
	29	32K-WORD	0B0000H - 0B7FFFH
Ξ	28	32K-WORD	0A8000H - 0AFFFFH
E	27 26	32K-WORD 32K-WORD	0A0000H - 0A7FFFH 098000H - 09FFFFH
Y	25	32K-WORD	090000H - 097FFFH
Ы	24	32K-WORD	088000H - 08FFFFH
K	23	32K-WORD	080000H - 087FFFH
E	22	32K-WORD	078000H - 07FFFFH
Έ	21 20	32K-WORD 32K-WORD	070000H - 077FFFH 068000H - 06FFFFH
PLANE0 (PARAMETER PLANE)	19	32K-WORD	060000H - 067FFFH
\mathbb{R}	18	32K-WORD	058000H - 05FFFFH
A	17	32K-WORD	050000H - 057FFFH
Ð	16	32K-WORD	048000H - 04FFFFH
E	15 14	32K-WORD	040000H - 047FFFH 038000H - 03FFFFH
Z	13	32K-WORD 32K-WORD	030000H - 037FFFH
Γ	12	32K-WORD	028000H - 02FFFFH
Р	11	32K-WORD	020000H - 027FFFH
	10	32K-WORD	018000H - 01FFFFH
	9	32K-WORD	010000H - 017FFFH 008000H - 00FFFFH
	8	32K-WORD 4K-WORD	008000H - 00FFFFH 007000H - 007FFFH
	6	4K-WORD 4K-WORD	006000H - 006FFFH
	5	4K-WORD	005000H - 005FFFH
	4	4K-WORD	004000H - 004FFFH
	3	4K-WORD	003000H - 003FFFH
	2	4K-WORD	002000H - 002FFFH 001000H - 001FFFH
	1	4K-WORD	

Figure 2.2. Memory Map (Bottom Parameter)

Table 3. Identifier Codes and OTP Address for Read Operation								
	Code	Address [A ₁₅ -A ₀]	Data [DQ ₁₅ -DQ ₀]	Notes				
Manufacturer Code	Manufacturer Code	0000H	00B0H	1				
Device Code	Device Code	0001H	$00B0H (BE_0 \# = V_{IL})$	1.0				
		0001H	$00B1H(BE_1 \# = V_{IL})$	1, 2				
Block Lock Configuration	Block is Unlocked		$DQ_0 = 0$	3				
Code	Block is Locked	Block	$DQ_0 = 1$	3				
	Block is not Locked-Down	- Address + 2	$DQ_1 = 0$	3				
	Block is Locked-Down		$DQ_1 = 1$	3				
Device Configuration Code	Partition Configuration Register	0006H	PCRC	1, 4				
OTP	OTP Lock	0080H	OTP-LK	1, 5, 7				
	OTP	0081-0088H	OTP	1, 6, 7				

NOTES:

1. The address A₂₁-A₁₆ are shown in below table for reading the manufacturer code, device code, device configuration code and OTP data.

2. Bank 0 (selected by $BE_0 = V_{IL}$) has its parameter blocks in the plane3 (The highest address within the bank). Bank 1 (selected by $BE_1 = V_{IL}$) has its parameter blocks in the plane0 (The lowest address within the bank).

- 3. Block Address = The beginning location of a block address within the partition to which the Read Identifier Codes/OTP command (90H) has been written.
- DQ_{15} - DQ_2 are reserved for future implementation.
- 4. PCRC=Partition Configuration Register Code.
- 5. OTP-LK=OTP Block Lock configuration.

6. OTP=OTP Block data.

7. When the data within OTP block is read, BE_0 must be V_{IL} . OTP block in Bank 1 (selected by BE_1 = V_{IL}) should not be used.

Partition C	Configuration I	Register ⁽²⁾	Address ⁽³⁾
PCR.10	PCR.9	PCR.8	[A ₂₁ -A ₁₆]
0	0	0	00H
0	0	1	00H or 10H
0	1	0	00H or 20H
1	0	0	00H or 30H
0	1	1	00H or 10H or 20H
1	1	0	00H or 20H or 30H
1	0	1	00H or 10H or 30H
1	1	1	00H or 10H or 20H or 30H

Table 4. Identifier Codes and OTP Address for Read Operation on Partition Configuration⁽¹⁾

NOTES:

- 1. The address to read the identifier codes or OTP data is dependent on the partition which is selected when writing the Read Identifier Codes/OTP command (90H).
- 2. Refer to Table 12 for the partition configuration register.
- 3. When the data within OTP block is read, BE_0 # must be V_{IL} . OTP block in Bank 1 (selected by BE_1 #= V_{IL}) should not be used.

[A21-A0]	
000088H	
	Customer Programmable Area
000085H	
000084H	
	Factory Programmed Area
000081H	
000080H	Reserved for Future Implementation (DQ15-DQ2)
Customer Progra	mmable Area Lock Bit (DQ1)

Figure 3. OTP Block Address Map for OTP Program⁽¹⁾ (The area outside 80H~88H cannot be used.)

NOTE:

1. When the OTP program operation is executed, write the OTP Program command with BE_0 # at V_{IL} . OTP block in Bank 1 (selected by BE_1 #= V_{IL}) should not be used.

				lable 5. D	us operat					
Mode		Notes	RST#	BE ₀ #	BE ₁ #	OE#	WE#	Address	V _{PP}	DQ ₀₋₁₅
	Bank 0			V _{IL}	V _{IH}					D.
Read Array	Bank 1	6	V _{IH}	V _{IH}	V _{IL}	V_{IL}	V_{IH}	Х	Х	D _{OUT}
	Inhibited			V _{IL}	V _{IL}					N/A
Output Disable			V _{IH}	V _{IL}	V _{IL}	V _{IH}	V _{IH}	Х	Х	High Z
	Bank 0			V _{IH}	V _{IL}					
Standby	Bank 1		V _{IH}	V _{IL}	V _{IH}	Х	Х	Х	Х	High Z
	Bank 0, 1			V _{IH}	V _{IH}					
Reset		3	V _{IL}	Х	Х	Х	Х	Х	Х	High Z
	Bank 0			V _{IL}	V _{IH}			See		See
Read Identifier Codes/OTP	Bank 1	6,9	V _{IH}	V _{IH}	V _{IL}	V _{IL}	V _{IH}	Table 3 and Table 4	Х	Table 3 and Table 4
	Inhibited			V _{IL}	V _{IL}					N/A
	Bank 0			V _{IL}	V _{IH}					See
Read Query	Bank 1	6,7	V _{IH}	V _{IH}	V _{IL}	V_{IL}	V_{IH}	See Appendix	Х	Appendix
	Inhibited			V _{IL}	V _{IL}			Appendix		N/A
	Bank 0			V _{IL}	V _{IH}					D
Write	Bank 1	4,5, 6,8	V _{IH}	V _{IH}	V _{IL}	V _{IH}	V _{IL}	Х	Х	D _{IN}
	Inhibited	0,0		V _{IL}	V _{IL}					N/A

Table 5. Bus Operation $(1, 2)$	Table 5.	Bus	Operation $(1,$	2)
---------------------------------	----------	-----	-----------------	----

NOTES:

1. Refer to DC Characteristics. When $V_{PP} \leq V_{PPLK}$, memory contents can be read, but cannot be altered. 2. X can be V_{IL} or V_{IH} for control pins and addresses, and V_{PPLK} or $V_{PPH1/2}$ for V_{PP} . See DC Characteristics for V_{PPLK} and V_{PPH1/2} voltages.

3. RST# at $GND\pm0.2V$ ensures the lowest power consumption.

4. Command writes involving block erase, (page buffer) program or OTP program are reliably executed when $V_{PP}=V_{PPH1/2}$ and $V_{CC}=2.7V-3.6V$. Command writes involving bank erase are reliably executed when $V_{PP}=V_{PPH1}$ and $V_{CC}=2.7V-3.6V$.

5. Refer to Table 6 for valid D_{IN} during a write operation.

6. Never hold OE# low and WE# low at the same timing.

7. Refer to Appendix of LH28F128BF series for more information about query code.

8. While the erase or program operation is executed in one bank, it is inhibited to execute the erase or program operation in another bank.

9. When the data within OTP block is read, BE_0 # must be V_{IL} . OTP block in Bank 1 (selected by $BE_1 #=V_{IL}$) should not be used.

Table 0. Command Definitions									
	Bus		First Bus Cycle			Second Bus Cycle			
Command	Cycles Req'd	Notes	Oper ⁽¹⁾	Addr ⁽²⁾	Data	Oper ⁽¹⁾	Addr ⁽²⁾	Data ⁽³⁾	
Read Array	1		Write	PA	FFH				
Read Identifier Codes/OTP	≥2	4,11	Write	PA	90H	Read	IA or OA	ID or OD	
Read Query	≥2	4	Write	PA	98H	Read	QA	QD	
Read Status Register	2		Write	PA	70H	Read	PA	SRD	
Clear Status Register	1		Write	PA	50H				
Block Erase	2	5	Write	BA	20H	Write	BA	D0H	
Bank Erase	2	5,9	Write	Х	30H	Write	Х	D0H	
Program	2	5,6	Write	WA	40H or 10H	Write	WA	WD	
Page Buffer Program	≥4	5,7	Write	WA	E8H	Write	WA	N-1	
Block Erase and (Page Buffer) Program Suspend	1	8,9	Write	PA	B0H				
Block Erase and (Page Buffer) Program Resume	1	8,9	Write	PA	D0H				
Set Block Lock Bit	2		Write	BA	60H	Write	BA	01H	
Clear Block Lock Bit	2	10	Write	BA	60H	Write	BA	D0H	
Set Block Lock-down Bit	2		Write	BA	60H	Write	BA	2FH	
OTP Program	2	9,11	Write	OA	СОН	Write	OA	OD	
Set Partition Configuration Register	2		Write	PCRC	60H	Write	PCRC	04H	

Table 6. Command $Definitions^{(12)}$

NOTES:

1. Bus operations are defined in Table 5.

2. All addresses which are written at the first bus cycle should be the same as the addresses which are written at the second bus cycle.

X=Any valid address. Bank erase is executed to the bank selected by BE_0 # or BE_1 #.

PA=Address within the selected partition.

IA=Identifier codes address (See Table 3 and Table 4).

QA=Query codes address. Refer to Appendix of LH28F128BF series for details.

BA=Address within the block being erased, set/cleared block lock bit or set block lock-down bit.

WA=Address of memory location for the Program command or the first address for the Page Buffer Program command. OA=Address of OTP block to be read or programmed (See Figure 3).

PCRC=Partition configuration register code presented on the address A_0 - A_{15} .

3. ID=Data read from identifier codes. (See Table 3 and Table 4).

QD=Data read from query database. Refer to Appendix of LH28F128BF series for details.

SRD=Data read from status register. See Table 10 and Table 11 for a description of the status register bits.

WD=Data to be programmed at location WA. Data is latched on the rising edge of WE# or $BE_0^{\#}$ or $BE_1^{\#}$ (whichever goes high first) during command write cycles.

OD=Data within OTP block. Data is latched on the rising edge of WE# or BE_0 # or BE_1 # (whichever goes high first) during command write cycles.

N-1=N is the number of the words to be loaded into a page buffer.

4. Following the Read Identifier Codes/OTP command, read operations access manufacturer code, device code, block lock configuration code, partition configuration register code and the data within OTP block (See Table 3 and Table 4). The Read Query command is available for reading CFI (Common Flash Interface) information.

5. Block erase, bank erase or (page buffer) program cannot be executed when the selected block is locked. Unlocked block can be erased or programmed when RST# is V_{IH}.

- 6. Either 40H or 10H are recognized by the CUI (Command User Interface) as the program setup.
- 7. Following the third bus cycle, input the program sequential address and write data of "N" times. Finally, input the any valid address within the target block to be programmed and the confirm command (D0H). Refer to Appendix of

LH28F128BF series for details.

- 8. If the program operation in one partition is suspended and the erase operation in other partition is also suspended, the suspended program operation should be resumed first, and then the suspended erase operation should be resumed next.
- 9. Bank erase and OTP program operations can not be suspended. The OTP Program command can not be accepted while the block erase operation is being suspended.
- 10. Following the Clear Block Lock Bit command, block which is not locked-down is unlocked when WP# is V_{IL}. When WP# is V_{IH}, lock-down bit is disabled and the selected block is unlocked regardless of lock-down configuration.
- 11. When the data within OTP block is read, BE_0 # must be V_{IL} . When the OTP program operation is executed, write the OTP Program command with BE_0 # at V_{IL} . OTP block in Bank 1 (selected by BE_1 #= V_{IL}) should not be used.
- 12. Commands other than those shown above are reserved by SHARP for future device implementations and should not be used.

		(2)			
State	WP#	$DQ_1^{(1)}$	$\mathrm{DQ}_{0}^{(1)}$	State Name	Erase/Program Allowed ⁽²⁾
[000]	0	0	0	Unlocked	Yes
$[001]^{(3)}$	0	0	1	Locked	No
[011]	0	1	1	Locked-down	No
[100]	1	0	0	Unlocked	Yes
[101] ⁽³⁾	1	0	1	Locked	No
[110] ⁽⁴⁾	1	1	0	Lock-down Disable	Yes
[111]	1	1	1	Lock-down Disable	No

NOTES:

1. $DQ_0=1$: a block is locked; $DQ_0=0$: a block is unlocked.

 $DQ_1=1$: a block is locked-down; $DQ_1=0$: a block is not locked-down.

- 2. Erase and program are general terms, respectively, to express: block erase, bank erase and (page buffer) program operations.
- 3. At power-up or device reset, all blocks default to locked state and are not locked-down, that is, [001] (WP#=0) or [101] (WP#=1), regardless of the states before power-off or reset operation.

4. When WP# is driven to V_{IL} in [110] state, the state changes to [011] and the blocks are automatically locked.

5. OTP (One Time Program) block has the lock function which is different from those described above.

	Curren	t State		Result after Lock Command Written (Next State)				
State	WP#	DQ ₁	DQ ₀	Set Lock ⁽¹⁾	Clear Lock ⁽¹⁾	Set Lock-down ⁽¹⁾		
[000]	0	0	0	[001]	No Change	[011] ⁽²⁾		
[001]	0	0	1	No Change ⁽³⁾	[000]	[011]		
[011]	0	1	1	No Change	No Change	No Change		
[100]	1	0	0	[101]	No Change	[111] ⁽²⁾		
[101]	1	0	1	No Change	[100]	[111]		
[110]	1	1	0	[111]	No Change	[111] ⁽²⁾		
[111]	1	1	1	No Change	[110]	No Change		

Table 8. Block Locking State Transitions upon Command Write⁽⁴⁾

NOTES:

1. "Set Lock" means Set Block Lock Bit command, "Clear Lock" means Clear Block Lock Bit command and "Set Lock-down" means Set Block Lock-Down Bit command.

2. When the Set Block Lock-Down Bit command is written to the unlocked block ($DQ_0=0$), the corresponding block is locked-down and automatically locked at the same time.

3. "No Change" means that the state remains unchanged after the command written.

4. In this state transitions table, assumes that WP# is not changed and fixed V_{IL} or V_{IH} .

D. C. J		Current S	State		Result after WP# Transition (Next State)		
Previous State	State	WP#	DQ ₁	DQ ₀	WP#= $0 \rightarrow 1^{(1)}$	WP#= $1 \rightarrow 0^{(1)}$	
-	[000]	0	0	0	[100]	-	
-	[001]	0	0	1	[101]	-	
[110] ⁽²⁾					[110]	-	
Other than $[110]^{(2)}$	[011]	0	1	1	[111]	-	
-	[100]	1	0	0	-	[000]	
-	[101]	1	0	1	-	[001]	
-	[110]	1	1	0	-	[011] ⁽³⁾	
-	[111]	1	1	1	-	[011]	

Table 9. Block Locking State Transitions upon WP# Transition⁽⁴⁾

NOTES:

1. "WP#=0 \rightarrow 1" means that WP# is driven to V_{IH} and "WP#=1 \rightarrow 0" means that WP# is driven to V_{IL}.

2. State transition from the current state [011] to the next state depends on the previous state.

3. When WP# is driven to V_{IL} in [110] state, the state changes to [011] and the blocks are automatically locked.

4. In this state transitions table, assumes that lock configuration commands are not written in previous, current and next state.

	R	R	R	R	R	R	R		
15	14	13	12	11	10	9	8		
WSMS	BESS	BEFCES	PBPOPS	VPPS	PBPSS	DPS	R		
7	6	5	4	3	2	1	0		
SR.15 - SR.8 = RESERVED FOR FUTURE ENHANCEMENTS (R)					NOT	TES:			
1 = Ready 0 = Busy		HINE STATUS		(Write State M be occupied by	indicates the st achine). Even if the other partiti s configuration.	the SR.7 is "1", ion when the de	, the WSM ma		
$1 = Block \\ 0 = Block $	Erase Suspende Erase in Progres	ss/Completed			o determine blo n or OTP progra BR.7="0".				
STAT 1 = Error in	US (BEFCES) n Block Erase o	D BANK ERAS r Bank Erase e or Bank Erase		If both SR.5 and SR.4 are "1"s after a block erase, bank era (page buffer) program, set/clear block lock bit, set bl lock-down bit, set partition configuration register attempt improper command sequence was entered.					
OTP 1 = Error in 0 = Succes	n (Page Buffer)	OGRAM AND ATUS (PBPOP Program or OT er) Program or (P Program	The WSM inte Block Erase, Program com	provide a contin progates and inc Bank Erase, (Pa nand sequences feedback when	licates the V _{PP} age Buffer) Pr s. SR.3 is not	level only aft ogram or O guaranteed		
$0 = V_{PP} OI$ SR.2 = (PAGE STAT 1 = (Page I	BUFFER) PRO US (PBPSS) Buffer) Program	SR.1 does not provide a continuous indication of bit. The WSM interrogates the block lock bit only a Erase, Bank Erase, (Page Buffer) Program or OT command sequences. It informs the system, depend attempted operation, if the block lock bit is set. R block lock configuration codes after writing					only after Blo OTP Progra epending on t et. Reading t ting the Re		
SR.1 = DEVIC 1 = Erase c	CE PROTECT S or Program Atte d Block, Operat		ompleted	Identifier Codes/OTP command indicates block loo status. SR.15 - SR.8 and SR.0 are reserved for future use and s be masked out when polling the status register.					

		Table 1	1. Extended St	atus Register De	finition				
R	R	R	R	R R R R					
15	14	13	12	11	8				
SMS	R	R	R	R	R	R	R		
7	6	5	4	3	2	1	0		
ENHANCE XSR.7 = STAT 1 = Page B	ESERVED FOR F MENTS (R) E MACHINE S uffer Program a uffer Program n	TATUS (SMS) vailable		XSR.7="1" ind If XSR.7 is "0" Buffer Program	NOT Page Buffer licates that the e , the command i n command (E8 uffer is available	Program cor entered comma s not accepted (H) should be	and is accepted. and a next Page		
XSR.6-0 = RESERVED FOR FUTURE ENHANCEMENTS (R)				XSR.6-0 are sked out when					

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		Table 12.	Partition Config	guration Regis	ter Definition				
R	R	R	R	R	PC2	PC1	PC0		
15	14	13	12	11	10	9	8		
R	R	R	R	R	R	R	R		
7	6	5	4	3	2	1	0		
PCR.15-11 = RESERVED FOR FUTURE ENHANCEMENTS (R)PCR.10-8 = PARTITION CONFIGURATION (PC2-0) 000 = No partitioning. Dual Work is not allowed. 001 = Plane1-3 are merged into one partition. (default in Bank 1 selected by $BE_1#=V_{IL}$) 010 = Plane 0-1 and Plane2-3 are merged into one partition respectively. 100 = Plane 0-2 are merged into one partition. (default in Bank 0 selected by $BE_0#=V_{IL}$) 011 = Plane 2-3 are merged into one partition. There are three partitions in this configuration. Dual work operation is available between any two partitions. 110 = Plane 1-2 are merged into one partitions. 110 = Plane 1-2 are merged into one partition. There are three partitions in this configuration. Dual work operation is available between any two partitions. 101 = Plane 1-2 are merged into one partition. There are three partitions in this configuration. Dual work operation is available between any two partitions.101 = Plane 1-2 are merged into one partition. There are three partitions in this configuration. Dual work operation is available between any two partitions.				See Figure 4 for the detail on partition configuration. PCR.15-11 and PCR.7-0 are reserved for future use and should be masked out when checking the partition					
PC2 PC1 PC0	PARTITION	NG FOR DUA	AL WORK	PC2 PC1 PC0	PARTITIO	NING FOR DU	AL WORK		
0 0 0		ARTITION0	PLANEO	0 1 1	PARTITIO	N2 PARTITION	11 PARTITION0		
0 0 1		LIANEI PLANEI	PARTITION0	1 1 0	PARTITION2 PAI	LIANE2	00000000000000000000000000000000000000		
0 1 0	BARTITION BITANE3	PLANE2	DIVIDITION0	1 0 1	PARTITION2	PLANE2 PLANE1	PARTITION0		
1 0 0	PARTITION1	PARTITIO FINET	0M PLANE0	1 1 1	PARTITION3 PART	LITION2 PARTITIC	DNI PARTITIONO		
		F	Figure 4. Partit	ion Configura	tion				

 Electrical Specifications Absolute Maximum Ratings[*] Operating Temperature During Read, Erase and Program40°C to +85°C ⁽¹⁾ 	*WARNING: Stressing the device beyond the "Absolute Maximum Ratings" may cause permanent damage. These are stress ratings only. Operation beyond the "Operating Conditions" is not recommended and extended exposure beyond the "Operating Conditions" may affect device reliability.
Storage Temperature During under Bias40°C to +85°C During non Bias65°C to +125°C	 NOTES: Operating temperature is for extended temperature product defined by this specification. All specified voltages are with respect to GND. Minimum DC voltage is -0.5V on input/output pins and -0.2V on V_{CC} and V_{PP} pins. During transitions,
Voltage On Any Pin (except V_{CC} and V_{PP})	 this level may undershoot to -2.0V for periods <20ns. Maximum DC voltage on input/output pins is V_{CC}+0.5V which, during transitions, may overshoot to V_{CC}+2.0V for periods <20ns. Maximum DC voltage on V_{PP} may overshoot to
V_{CC} Supply Voltage0.2V to +3.9V ⁽²⁾ V_{PP} Supply Voltage0.2V to +12.6V ^(2, 3, 4)	 +13.0V for periods <20ns. V_{PP} erase/program voltage is normally 2.7V-3.6V. Applying 11.7V-12.3V to V_{PP} during erase/program can be done for a maximum of 1,000 cycles on the main blocks and 1,000 cycles on the parameter blocks. V may be connected to 11.7V 12.3V for a total of 80.
Output Short Circuit Current 100mA ⁽⁵⁾	 V_{PP} may be connected to 11.7V-12.3V for a total of 80 hours maximum. 5. Output shorted for no more than one second. No more than one output shorted at a time.

1.2 Operating Conditions

Parameter	Symbol	Min.	Тур.	Max.	Unit	Notes
Operating Temperature	T _A	-40	+25	+85	°C	
V _{CC} Supply Voltage	V _{CC}	2.7	3.0	3.6	V	1
V _{PP} Voltage when Used as a Logic Control	V _{PPH1}	1.65	3.0	3.6	V	1
V _{PP} Supply Voltage	V _{PPH2}	11.7	12	12.3	V	1, 2
Main Block Erase Cycling: V _{PP} =V _{PPH1}		100,000			Cycles	
Parameter Block Erase Cycling: V _{PP} =V _{PPH1}		100,000			Cycles	
Main Block Erase Cycling: V _{PP} =V _{PPH2} , 80 hrs.				1,000	Cycles	
Parameter Block Erase Cycling: $V_{PP}=V_{PPH2}$, 80 hrs.				1,000	Cycles	
Maximum V _{PP} hours at V _{PPH2}				80	Hours	

NOTES:

1. See DC Characteristics tables for voltage range-specific specification.

2. Applying V_{pp}=11.7V-12.3V during a erase or program can be done for a maximum of 1,000 cycles on the main blocks and 1,000 cycles on the parameter blocks. A permanent connection to V_{PP}=11.7V-12.3V is not allowed and can cause damage to the device.

1.2.1 Capacitance⁽¹⁾ (T_A =+25°C, f=1MHz)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Input Capacitance	C _{IN}	V _{IN} =0.0V		12	16	pF
Output Capacitance	C _{OUT}	V _{OUT} =0.0V		20	24	pF

NOTE:

1. Sampled, not 100% tested.

1.2.2 AC Input/Output Test Conditions

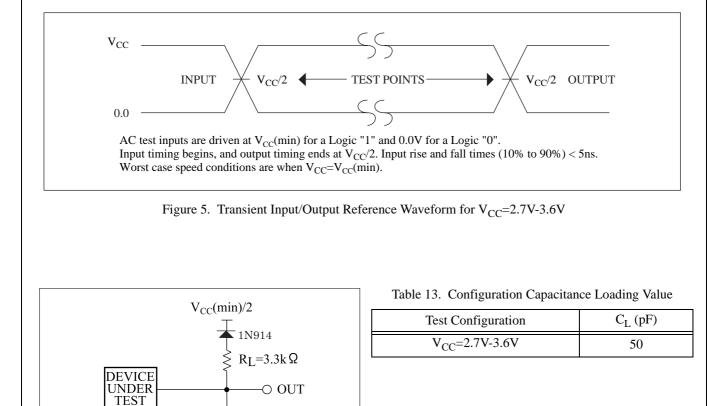


Figure 6. Transient Equivalent Testing Load Circuit

CL Includes Jig Capacitances. C_L

1.2.3 DC Characteristics

Symbol	Paran	neter	Notes	Min.	Тур.	Max.	Unit	Test Conditions
I _{LI}	Input Load Current		1	-2.0		+2.0	μΑ	V _{CC} =V _{CC} Max.,
I _{LO}	Output Leakage Cur	rent	1	-2.0		+2.0	μΑ	V _{IN} /V _{OUT} =V _{CC} or GND
I _{CCS}	V _{CC} Standby Curren	t	1		8	40	μΑ	$V_{CC}=V_{CC}Max.,$ BE ₀ #=BE ₁ #=RST#= $V_{CC}\pm 0.2V,$ WP#= V_{CC} or GND
I _{CCAS}	V _{CC} Automatic Pow	er Savings Current	1,4		8	40	μΑ	$V_{CC}=V_{CC}Max.,$ BE ₀ # or BE ₁ #= GND $\pm 0.2V$, WP#=V _{CC} or GND
I _{CCD}	V _{CC} Reset Power-Do	own Current	1		8	40	μΑ	RST#=GND±0.2V
T	Average V _{CC} Read Current Normal Mode		1,7		15	25	mA	V _{CC} =V _{CC} Max., BE ₀ # or BE ₁ #=V _{IL} ,
I _{CCR}	Average V _{CC} Read Current Page Mode	8 Word Read	1,7		5	10	mA	OE#=V _{IH} , f=5MHz
т	V (De se Deeffer) D	contraction and	1,5,7		20	60	mA	V _{PP} =V _{PPH1}
I _{CCW}	V _{CC} (Page Buffer) P	logram Current	1,5,7		10	20	mA	V _{PP} =V _{PPH2}
т	V _{CC} Block Erase, Ba	ank	1,5,7		10	30	mA	V _{PP} =V _{PPH1}
I _{CCE}	Erase Current		1,5,7		10	30	mA	V _{PP} =V _{PPH2}
I _{CCWS} I _{CCES}	V _{CC} (Page Buffer) P Block Erase Suspend		1,2,7		10	200	μΑ	BE0#=BE1#=VIH
I _{PPS} I _{PPR}	V _{PP} Standby or Read	l Current	1,6,7		4	10	μΑ	V _{PP} ≤V _{CC}
T	V _{PP} (Page Buffer) Pr	rogram Current	1,5,6,7		2	5	μΑ	V _{PP} =V _{PPH1}
I _{PPW}	· pp (1 age Duilet) f		1,5,6,7		10	30	mA	V _{PP} =V _{PPH2}
Inne	V _{PP} Block Erase, Ba	nk	1,5,6,7		2	5	μA	V _{PP} =V _{PPH1}
I _{PPE}	Erase Current		1,5,6,7		5	15	mA	V _{PP} =V _{PPH2}
I _{PPWS}	V _{PP} (Page Buffer) Pr	rogram	1,6,7		2	5	μΑ	V _{PP} =V _{PPH1}
PPWS	Suspend Current		1,6,7		10	200	μΑ	V _{PP} =V _{PPH2}
IDDEC	V _{PP} Block Erase Sus	spend Current	1,6,7		2	5	μΑ	V _{PP} =V _{PPH1}
I _{PPES}	PP DIOCK Erase Sus	pena Current	1,6,7		10	200	μΑ	V _{PP} =V _{PPH2}

V_{CC}=2.7V-3.6V

DC Characteristics (Continued)

		·	2.7 * 2.0 *				
Symbol	Parameter	Notes	Min.	Тур.	Max.	Unit	Test Conditions
V _{IL}	Input Low Voltage	5	-0.4		0.4	V	
V _{IH}	Input High Voltage	5	2.4		V _{CC} + 0.4	V	
V _{OL}	Output Low Voltage	5			0.2	V	V _{CC} =V _{CC} Min., I _{OL} =100µA
V _{OH}	Output High Voltage	5	V _{CC} -0.2			V	V _{CC} =V _{CC} Min., I _{OH} =-100µA
V _{PPLK}	V _{PP} Lockout during Normal Operations	3,5,6			0.4	V	
V _{PPH1}	V _{PP} during Block Erase, Bank Erase, (Page Buffer) Program or OTP Program Operations		1.65	3.0	3.6	V	
V _{PPH2}	V _{PP} during Block Erase, (Page Buffer) Program or OTP Program Operations	6	11.7	12	12.3	V	
V _{LKO}	V _{CC} Lockout Voltage		1.5			V	

V_{CC}=2.7V-3.6V

NOTES:

1. All currents are in RMS unless otherwise noted. Typical values are the reference values at V_{CC} =3.0V and T_A =+25°C unless V_{CC} is specified.

2. I_{CCWS} and I_{CCES} are specified with the device de-selected. If read or (page buffer) program is executed while in block erase suspend mode, the device's current draw is the sum of I_{CCES} and I_{CCR} or I_{CCW} . If read is executed while in (page buffer) program suspend mode, the device's current draw is the sum of I_{CCWS} and I_{CCR} .

3. Block erase, bank erase, (page buffer) program and OTP program are inhibited when V_{PP}≤V_{PPLK}, and not guaranteed in the range between V_{PPLK}(max.) and V_{PPH1}(min.), between V_{PPH1}(max.) and V_{PPH2}(min.) and above V_{PPH2}(max.).

4. The Automatic Power Savings (APS) feature automatically places the device in power save mode after read cycle completion. Standard address access timings (t_{AVQV}) provide new data when addresses are changed.

5. Sampled, not 100% tested.

6. V_{PP} is not used for power supply pin. With $V_{PP} \leq V_{PPLK}$, block erase, bank erase, (page buffer) program and OTP program cannot be executed and should not be attempted.

Applying $12V\pm0.3V$ to V_{PP} provides fast erasing or fast programming mode. In this mode, V_{PP} is power supply pin and supplies the memory cell current for block erasing and (page buffer) programming. Use similar power supply trace widths and layout considerations given to the V_{CC} power bus.

Applying $12V\pm0.3V$ to V_{PP} during erase/program can only be done for a maximum of 1,000 cycles on each block. V_{PP} may be connected to $12V\pm0.3V$ for a total of 80 hours maximum.

7. The operating current in dual work is the sum of the operating current (read, erase, program) in each plane.

1.2.4 AC Characteristics - Read-Only Operations⁽¹⁾

Symbol	Parameter	Notes	Min.	Max.	Unit
t _{AVAV}	Read Cycle Time		90		ns
t _{AVQV}	Address to Output Delay			90	ns
t _{ELQV}	BE_0 # or BE_1 # to Output Delay	3		90	ns
t _{APA}	Page Address Access Time			35	ns
t _{GLQV}	OE# to Output Delay	3		20	ns
t _{PHQV}	RST# High to Output Delay			150	ns
t _{EHQZ} , t _{GHQZ}	BE_0 or BE_1 or OE to Output in High Z, Whichever Occurs First	2		20	ns
t _{ELQX}	BE_0 # or BE_1 # to Output in Low Z	2	0		ns
t _{GLQX}	OE# to Output in Low Z	2	0		ns
t _{OH}	Output Hold from First Occurring Address, BE_0 # or BE_1 # or OE # change	2	0		ns
t _{AVEL} , t _{AVGL}	Address Setup to BE_0 # or BE_1 #, OE# Going Low for Reading Status Register	4, 6	10		ns
$t_{\rm ELAX}, t_{\rm GLAX}$	Address Hold from BE_0 # or BE_1 #, OE # Going Low for Reading Status Register	5, 6	30		ns
t _{EHEL} , t _{GHGL}	BE_0 # or BE_1 #, OE# Pulse Width High for Reading Status Register	6	30		ns

 $V_{CC}=2.7V-3.6V, T_{A}=-40^{\circ}C \text{ to }+85^{\circ}C$

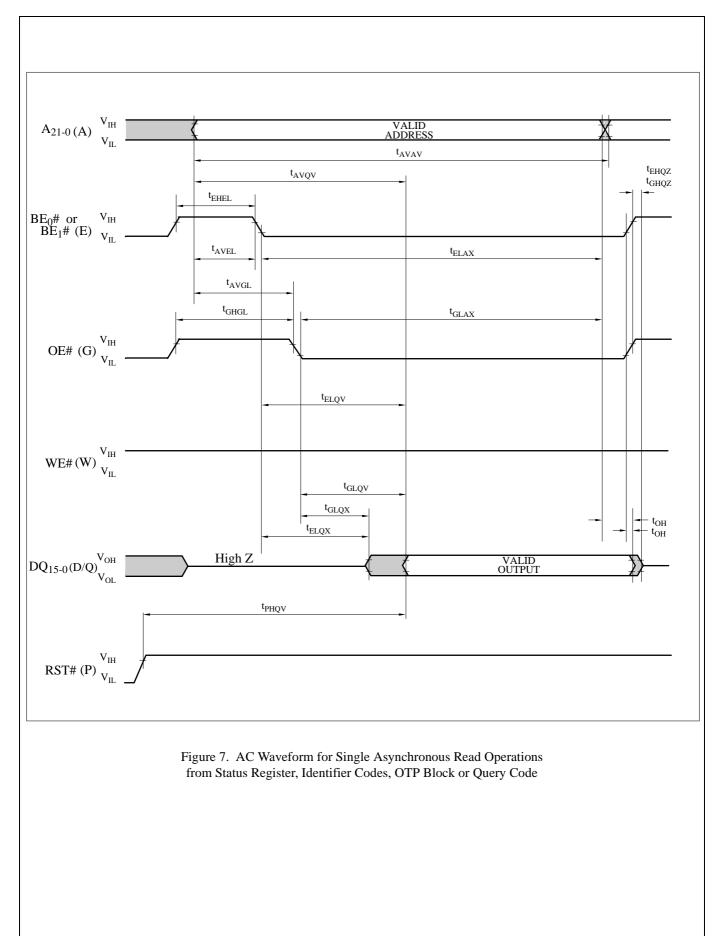
NOTES:

1. See AC input/output reference waveform for timing measurements and maximum allowable input slew rate.

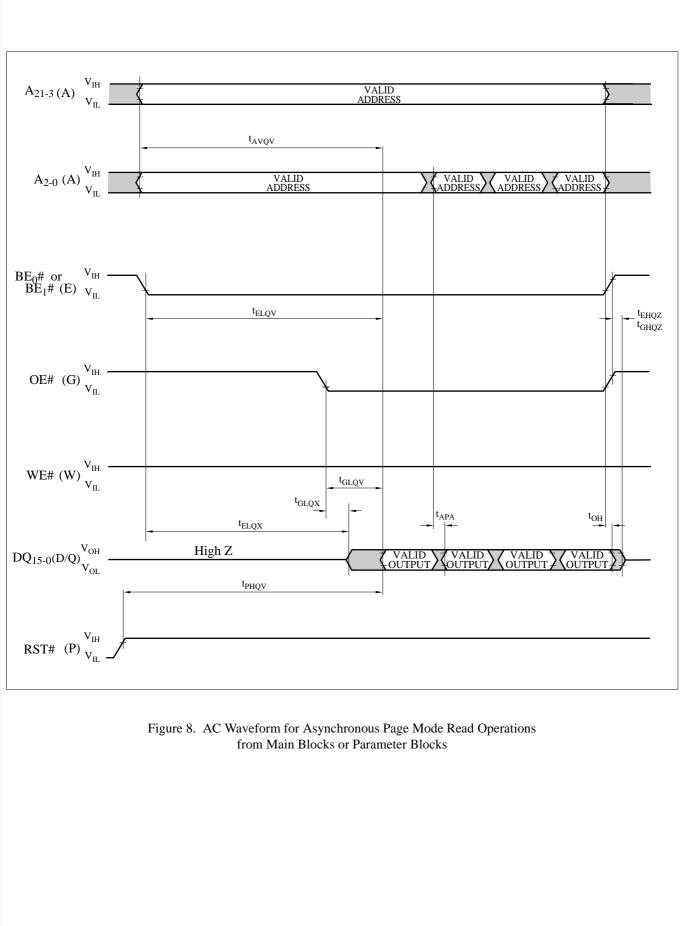
2. Sampled, not 100% tested.

3. OE# may be delayed up to t_{ELQV} — t_{GLQV} after the falling edge of BE₀# or BE₁# without impact to t_{ELQV} . 4. Address setup time (t_{AVEL} , t_{AVGL}) is defined from the falling edge of BE₀# or BE₁# or OE# (whichever goes low last). 5. Address hold time (t_{ELAX} , t_{GLAX}) is defined from the falling edge of BE₀# or BE₁# or OE# (whichever goes low last). 6. Specifications t_{AVEL} , t_{AVGL} , t_{ELAX} , t_{GLAX} and t_{EHEL} , t_{GHGL} for read operations apply to only status register read operations.









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1.2.5 AC Characteristics - Write Operations^{(1), (2)}

Symbol	Parameter	Notes	Min.	Max.	Unit
t _{AVAV}	Write Cycle Time		90		ns
t _{PHWL} (t _{PHEL})	RST# High Recovery to WE# (BE_0 # or BE_1 #) Going Low	3	150		ns
$t_{ELWL} (t_{WLEL})$	BE_0 # or BE_1 # (WE#) Setup to WE# (BE_0 # or BE_1 #) Going Low		0		ns
t _{WLWH} (t _{ELEH})	WE# (BE $_0$ # or BE $_1$ #) Pulse Width	4	60		ns
t _{DVWH} (t _{DVEH})	Data Setup to WE# (BE_0 # or BE_1 #) Going High	8	40		ns
t_{AVWH} (t_{AVEH})	Address Setup to WE# (BE_0 # or BE_1 #) Going High	8	50		ns
t _{WHEH} (t _{EHWH})	$\begin{array}{c} BE_0 \# \text{ or } BE_1 \# \text{ (WE\#) Hold from WE\# (BE_0 \# \text{ or } BE_1 \#)} \\ High \end{array}$		0		ns
t _{WHDX} (t _{EHDX})	Data Hold from WE# (BE_0 # or BE_1 #) High		0		ns
$t_{WHAX} (t_{EHAX})$	Address Hold from WE# (BE_0 # or BE_1 #) High		0		ns
t_{WHWL} (t_{EHEL})	WE# (BE ₀ # or BE ₁ #) Pulse Width High	5	30		ns
$t_{\rm SHWH} (t_{\rm SHEH})$	WP# High Setup to WE# (BE_0 # or BE_1 #) Going High	3	0		ns
t _{VVWH} (t _{VVEH})	V_{PP} Setup to WE# (BE ₀ # or BE ₁ #) Going High	3	200		ns
t_{WHGL} (t_{EHGL})	Write Recovery before Read		30		ns
t _{QVSL}	WP# High Hold from Valid SRD	3, 6	0		ns
t _{QVVL}	V _{PP} Hold from Valid SRD	3, 6	0		ns
t _{WHR0} (t _{EHR0})	WE# (BE ₀ # or BE ₁ #) High to SR.7 Going "0"	3, 7		t_{AVQV}^+ 50	ns

 $V_{CC}=2.7V-3.6V, T_{A}=-40^{\circ}C \text{ to }+85^{\circ}C$

NOTES:

1. The timing characteristics for reading the status register during block erase, bank erase, (page buffer) program and OTP program operations are the same as during read-only operations. Refer to AC Characteristics for read-only operations.

2. A write operation can be initiated and terminated with either BE_0 or BE_1 or WE.

3. Sampled, not 100% tested.

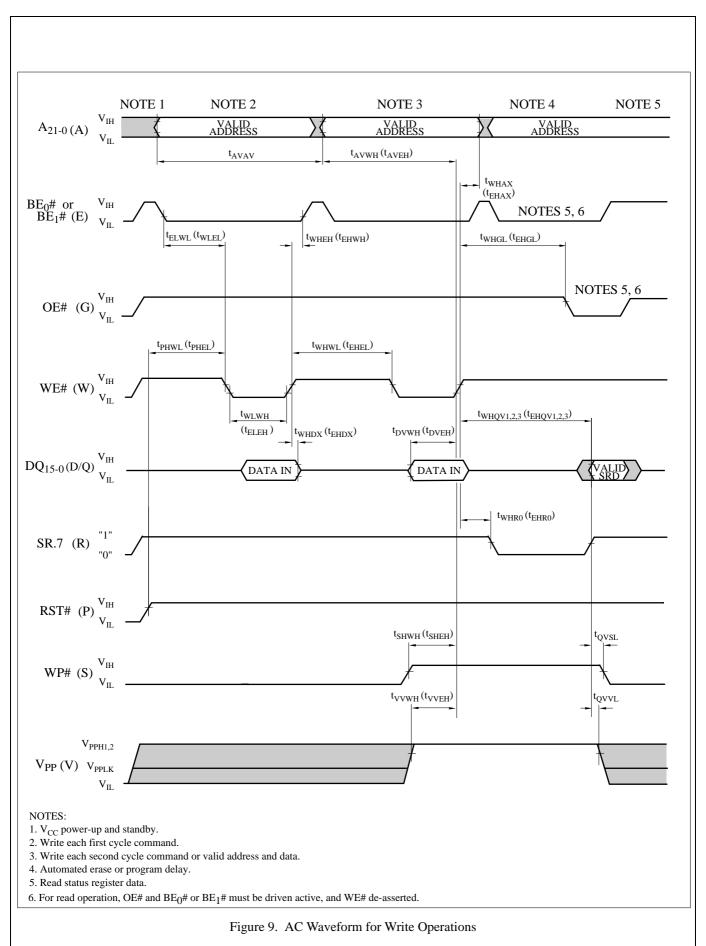
4. Write pulse width (t_{WP}) is defined from the falling edge of BE₀# or BE₁# or WE# (whichever goes low last) to the rising edge of $BE_0^{\#}$ or $BE_1^{\#}$ or $WE^{\#}$ (whichever goes high first). Hence, $t_{WP} = t_{WLWH} = t_{ELEH} = t_{WLEH} = t_{ELWH}$. 5. Write pulse width high (t_{WPH}) is defined from the rising edge of $BE_0^{\#}$ or $BE_1^{\#}$ or $WE^{\#}$ (whichever goes high first) to the

falling edge of BE_0 # or BE_1 # or WE# (whichever goes low last). Hence, $t_{WPH}=t_{WHWL}=t_{EHEL}=t_{WHEL}=t_{EHWL}$. 6. V_{PP} should be held at $V_{PP}=V_{PPH1/2}$ until determination of block erase, (page buffer) program or OTP program success (SR.1/3/4/5=0) and held at $V_{PP}=V_{PPH1}$ until determination of bank erase success (SR.1/3/5=0).

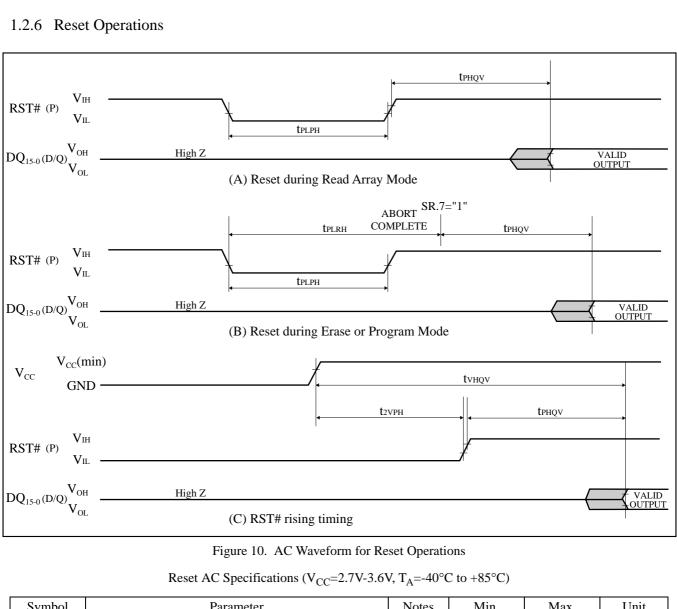
7. t_{WHR0} (t_{EHR0}) after the Read Query or Read Identifier Codes/OTP command= t_{AVOV} +100ns.

8. Refer to Table 6 for valid address and data for block erase, bank erase, (page buffer) program, OTP program or lock bit configuration.





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Parameter	Notes	Min.	Max.	Unit
RST# Low to Reset during Read (RST# should be low during power-up.)	1, 2, 3	100		ns
RST# Low to Reset during Erase or Program	1, 3, 4		22	μs
V _{CC} 2.7V to RST# High	1, 3, 5	100		ns
V _{CC} 2.7V to Output Delay	3		1	ms
(RST# should be low during power-up.) RST# Low to Reset during Erase or Program W _{CC} 2.7V to RST# High	RST# should be low during power-up.)1, 2, 3RST# Low to Reset during Erase or Program1, 3, 4V _{CC} 2.7V to RST# High1, 3, 5	RST# should be low during power-up.)1, 2, 3100RST# Low to Reset during Erase or Program1, 3, 4V _{CC} 2.7V to RST# High1, 3, 5100	RST# should be low during power-up.)1, 2, 3100RST# Low to Reset during Erase or Program1, 3, 422V _{CC} 2.7V to RST# High1, 3, 5100

NOTES:

1. A reset time, t_{PHQV}, is required from the later of SR.7 going "1" or RST# going high until outputs are valid. Refer to AC Characteristics - Read-Only Operations for t_{PHQV}.

2. t_{PLPH} is <100ns the device may still reset but this is not guaranteed.

3. Sampled, not 100% tested.

4. If RST# asserted while a block erase, bank erase, (page buffer) program or OTP program operation is not executing, the reset will complete within 100ns.

5. When the device power-up, holding RST# low minimum 100ns is required after V_{CC} has been in predefined range and also has been in stable there.

1.2.7 Block Erase, Bank Erase, (Page Buffer) Program and OTP Program Performance⁽³⁾

	e	.C								
Symbol	l Parameter		Page Buffer Command is	V _{PP} =V _{PPH1} (In System)		V _{PP} =V _{PPH2} (In Manufacturing)			Unit	
			Used or not Used	Min.	Тур. ⁽¹⁾	Max. ⁽²⁾	Min.	Тур. ⁽¹⁾	Max. ⁽²⁾	
twop	4K-Word Parameter Block	2	Not Used		0.05	0.3		0.04	0.12	s
t _{WPB}	Program Time	2	Used		0.03	0.12		0.02	0.06	s
tun m	32K-Word Main Block	2	Not Used		0.38	2.4		0.31	1.0	s
t _{WMB}	Program Time	2	Used		0.24	1.0		0.17	0.5	s
t _{WHQV1} /	Word Program Time	2	Not Used		11	200		9	185	μs
t _{EHQV1}		2	Used		7	100		5	90	μs
t _{WHOV1} / t _{EHOV1}	OTP Program Time	2, 6	Not Used		36	400		27	185	μs
t _{WHQV2} / t _{EHQV2}	4K-Word Parameter Block Erase Time	2	-		0.3	4		0.2	4	S
t _{WHQV3} / t _{EHQV3}	32K-Word Main Block Erase Time	2	-		0.6	5		0.5	5	S
	Bank Erase Time	2			80	700				S
t _{WHRH1} / t _{EHRH1}	(Page Buffer) Program Suspend Latency Time to Read	4	-		5	10		5	10	μs
t _{WHRH2} / t _{EHRH2}	Block Erase Suspend Latency Time to Read	4	-		5	20		5	20	μs
t _{ERES}	Latency Time from Block Erase Resume Command to Block Erase Suspend Command	5	-	500			500			μs

 V_{CC} =2.7V-3.6V, T_{A} =-40°C to +85°C

NOTES:

1. Typical values measured at V_{CC}=3.0V, V_{PP}=3.0V or 12V, and T_A=+25°C. Assumes corresponding lock bits are not set. Subject to change based on device characterization.

2. Excludes external system-level overhead.

3. Sampled, but not 100% tested.

4. A latency time is required from writing suspend command (WE# or BE₀# or BE₁# going high) until SR.7 going "1".

5. If the interval time from a Block Erase Resume command to a subsequent Block Erase Suspend command is shorter than t_{ERES} and its sequence is repeated, the block erase operation may not be finished.

6. When the OTP program operation is executed, write the OTP Program command with BE_0 at V_{IL} .

OTP block in Bank 1 (selected by $BE_1 #=V_{IL}$) should not be used.

2 Related Document Information⁽¹⁾

Document No.	Document Name
FUM00701	LH28F128BF series Appendix

NOTE:

1. International customers should contact their local SHARP or distribution sales offices.

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3	Deelroge and	maalrima	manification
3	Package and	packing	specification

[Applicability]

This specification applies to IC package of the LEAD-FREE delivered as a standard specification.

- 1. Storage Conditions.
 - 1-1. Storage conditions required before opening the dry packing.
 - Normal temperature : $5 \sim 40 ^{\circ} \text{C}$
 - Normal humidity : 80%(Relative humidity) max.
 - *"Humidity" means "Relative humidity"

1-2. Storage conditions required after opening the dry packing.

In order to prevent moisture absorption after opening, ensure the following storage conditions apply:

- (1) Storage conditions for one-time soldering. (Convection reflow^{*1}, IR/Convection reflow.^{*1}, or Manual soldering.)
 - Temperature : 5∼25℃
 - Humidity : 60% max.
 - Period : 72 hours max. after opening.
- (2) Storage conditions for two-time soldering. (Convection reflow^{*1}, IR/Convection reflow.^{*1})
 - a. Storage conditions following opening and prior to performing the 1st reflow.
 - Temperature : $5 \sim 25^{\circ}$ C
 - Humidity : 60% max.
 - Period : 72 hours max. after opening.
 - b. Storage conditions following completion of the 1st reflow and prior to performing the 2nd reflow.
 - Temperature : 5∼25℃
 - Humidity : 60% max.
 - Period : 72 hours max. after completion of the 1st reflow.

^{*1}:Air or nitrogen environment.

1-3. Temporary storage after opening.

To re-store the devices before soldering, do so only once and use a dry box or place desiccant (with a blue humidity indicator) with the devices and perform dry packing again using heat-sealing.

The storage period, temperature and humidity must be as follows :

- (1) Storage temperature and humidity.
 - %1: External atmosphere temperature and humidity of the dry packing.

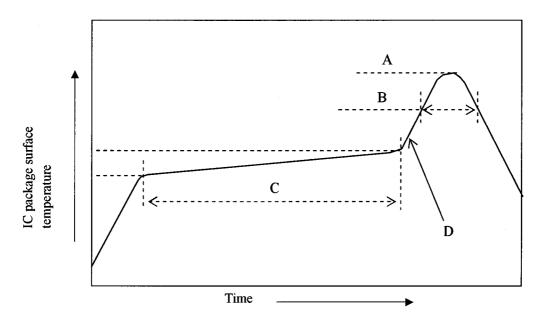
First opening	← X1 → H	Re-sealing ∢ Y —	> Re-opening -	X2	► Mounting
→ X1 Temperature : 5~40°C Humidity : 80% max.	5∼25℃ 60% max.	→ ×1 5~4 80% max.		5~25℃ 60% max.	O

- (2) Storage period.
 - X1 + X2: Refer to Section 1-2(1) and (2)a, depending on the mounting method.

• Y : Two weeks max.

- 2. Baking Condition.
 - (1) Situations requiring baking before mounting.
 - Storage conditions exceed the limits specified in Section 1-2 or 1-3.
 - · Humidity indicator in the desiccant was already red (pink) when opened.
 - (Also for re-opening.)
 - (2) Recommended baking conditions.
 - Baking temperature and period :
 - 120°C for 16~24 hours.
 - The above baking conditions apply since the trays are heat-resistant.
 - (3) Storage after baking.
 - After baking, store the devices in the environment specified in Section 1-2 and mount immediately.
- 3. Surface mount conditions.
 - The following soldering condition are recommended to ensure device quality.
- 3-1.Soldering.
- (1) Convection reflow or IR/Convection. (one-time soldering or two-time soldering in air or nitrogen environment)
 - Temperature and period :
 - A) Peak temperature.
 - B) Heating temperature.
 - C) Preheat temperature.
 - D) Temperature increase rate.
 - Measuring point : IC package surface.
 - · Temperature profile:

250℃ max. 40 to 60 seconds as 220℃ It is 150 to 200℃, and is 120±30 seconds It is 1 to 3℃/seconds



- (2) Manual soldering (soldering iron) (one-time soldering only) Soldering iron should only touch the IC's outer leads.
 - Temperature and period :
 - 350°C max. for 3 seconds / pin max.
 - (Soldering iron should only touch the IC's outer leads.)
 - Measuring point : Soldering iron tip.
- 4. Condition for removal of residual flux.
 - (1) Ultrasonic washing power : 25 watts / liter max.
 - (2) Washing time : Total 1 minute max.
 - (3) Solvent temperature : $15 \sim 40^{\circ}$ C

5. Package outline specification.

Refer to the attached drawing.

(Plastic body dimensions do not include burr of resin.)

The contents of LEAD-FREE TYPE application of the specifications. (*2)

6. Markings.

6-1. Marking details. (The information on the package should be given as follows.)

(1) Product name : LH28F128BFHED-PWTLZ8 (2) Company name : SHARP (3) Date code (Example) YYWW XXX : YY Denotes the production year. (Last two digits of the year.) \rightarrow WW \rightarrow Denotes the production week. $(01 \cdot 02 \cdot \sim \cdot 52 \cdot 53)$ XXX Denotes the production ref. code ($1 \sim 3$ digits). \rightarrow (4) "JAPAN" indicates the country of origin.

6-2. Marking layout.

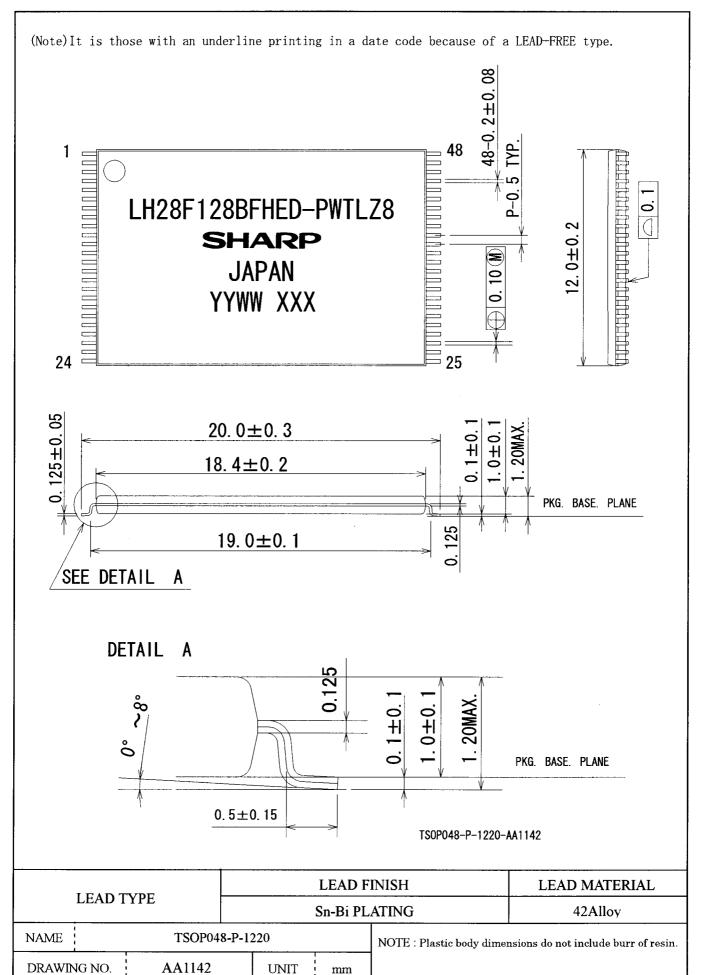
The layout is shown in the attached drawing.

(However, this layout does not specify the size of the marking character and marking position.)

LEAD FINISH or BALL TYPE	LEAD-FREE TYPE (Sn-Bi)
DATE CODE	They are those with an underline.
The word of "LEAD FREE" is printed on the packing label	Printed

*2 The contents of LEAD-FREE TYPE application of the specifications.

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- SHARP
 - 7.Packing Specifications (Dry packing for surface mount packages.) 7-1.Packing materials.

Material name	Material specifications	Purpose
Inner carton	Cardboard (960 devices / inner carton	Packing the devices.
	max.)	(10 trays / inner carton)
Tray	Conductive plastic (96 devices / tray)	Securing the devices.
Upper cover tray	Conductive plastic (1 tray / inner carton)	Securing the devices.
Laminated aluminum Aluminum polyethylene		Keeping the devices dry.
bag		
Desiccant	Silica gel	Keeping the devices dry.
Label	Paper	Indicates part number,
		quantity, and packed date.
PP band	Polypropylene (3 pcs. / inner carton)	Securing the devices.
Outer carton	Cardboard (3840 devices / outer carton	Outer packing.
	max.)	

(Devices must be placed on the tray in the same direction.)

7-2.Outline dimension of tray.

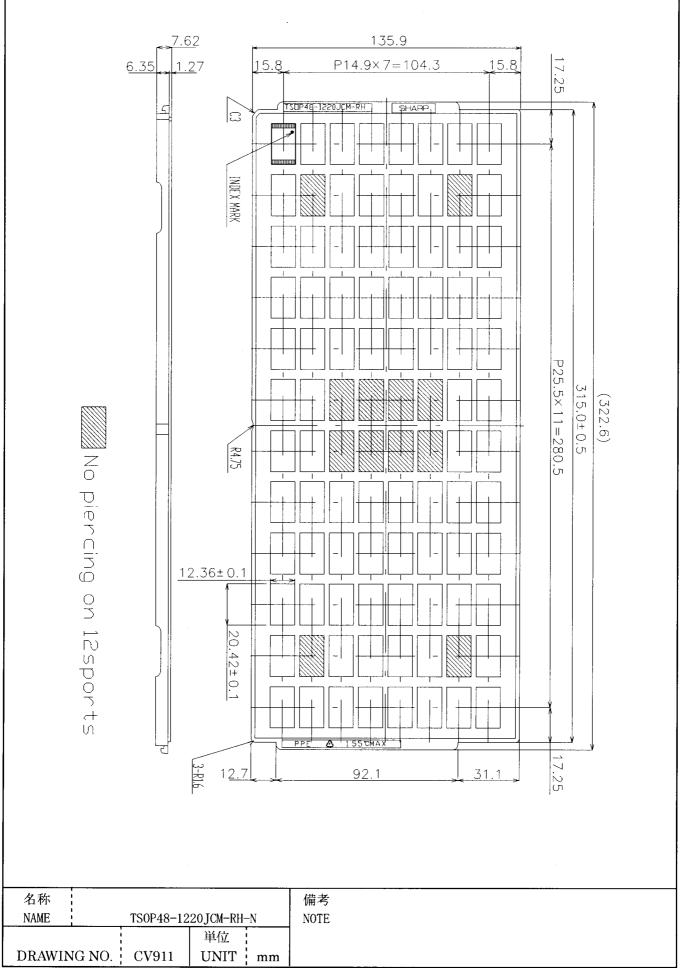
Refer to the attached drawing.

7-3.Outline dimension of carton.

Refer to the attached drawing.

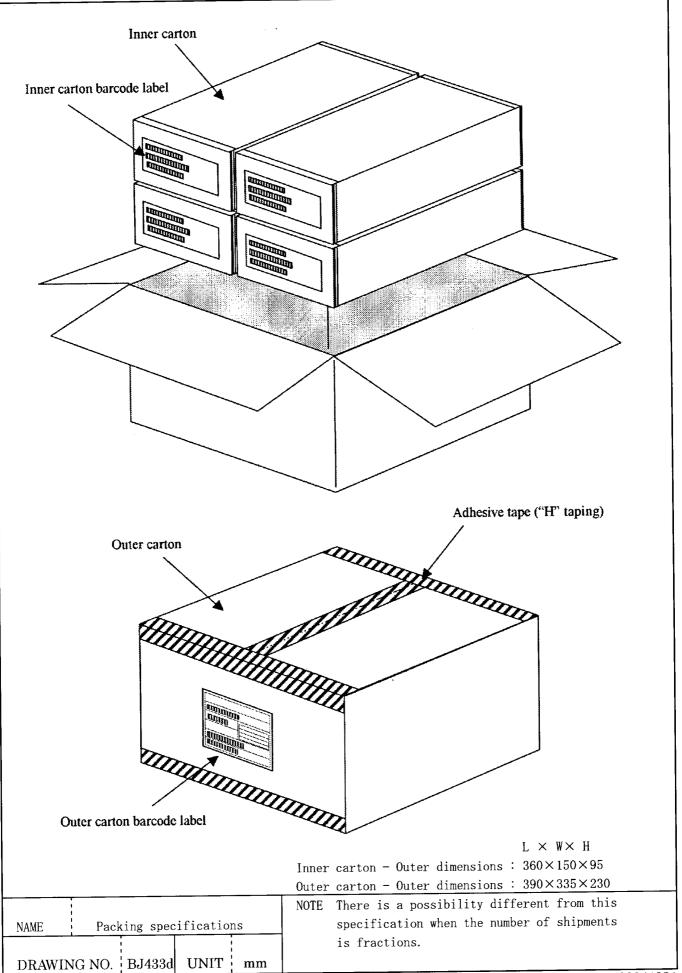
- 8. Precautions for use.
 - (1) Opening must be done on an anti-ESD treated workbench. All workers must also have undergone anti-ESD treatment.
 - (2) The trays have undergone either conductive or anti-ESD treatment. If another tray is used, make sure it has also undergone conductive or anti-ESD treatment.
 - (3) The devices should be mounted within one year of the date of delivery.

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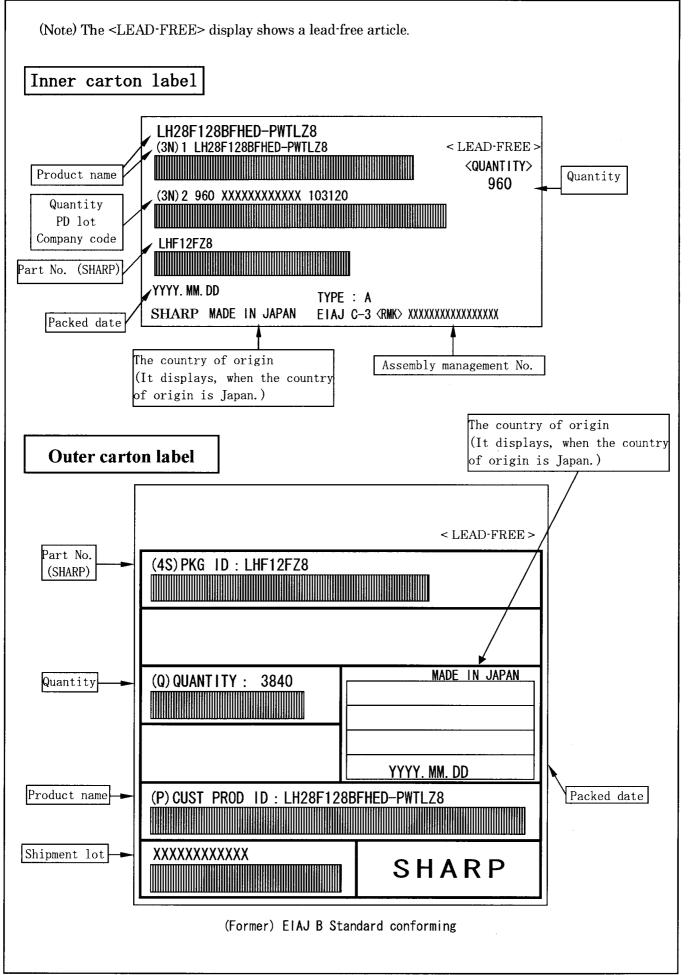


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A-1 RECOMMENDED OPERATING CONDITIONS

A-1.1 At Device Power-Up

AC timing illustrated in Figure A-1 is recommended for the supply voltages and the control signals at device power-up. If the timing in the figure is ignored, the device may not operate correctly.

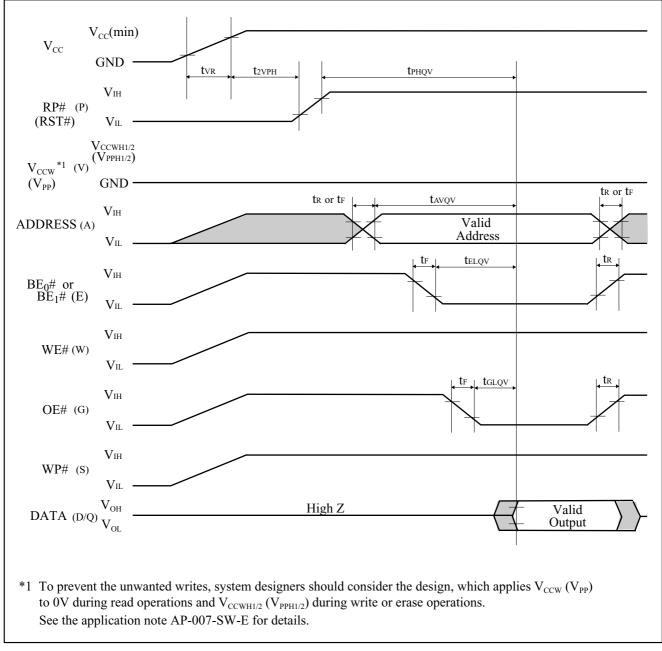


Figure A-1. AC Timing at Device Power-Up

For the AC specifications t_{VR} , t_R , t_F in the figure, refer to the next page. See the "ELECTRICAL SPECIFICATIONS" described in specifications for the supply voltage range, the operating temperature and the AC specifications not shown in the next page.

A-1.1.1 Rise and Fall Time

Symbol	Parameter	Notes	Min.	Max.	Unit
t _{VR}	V _{CC} Rise Time	1	0.5	30000	μs/V
t _R	Input Signal Rise Time	1, 2		1	μs/V
t _F	Input Signal Fall Time	1, 2		1	μs/V

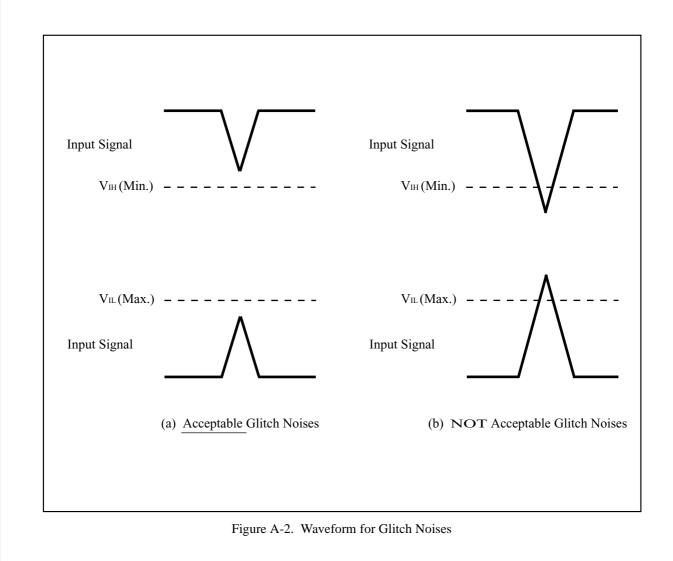
NOTES:

1. Sampled, not 100% tested.

2. This specification is applied for not only the device power-up but also the normal operations.

A-1.2 Glitch Noises

Do not input the glitch noises which are below V_{IH} (Min.) or above V_{IL} (Max.) on address, data, reset, and control signals, as shown in Figure A-2 (b). The acceptable glitch noises are illustrated in Figure A-2 (a).



See the "DC CHARACTERISTICS" described in specifications for V_{IH} (Min.) and V_{IL} (Max.).

A-2 RELATED DOCUMENT INFORMATION⁽¹⁾

Document No.	Document Name
AP-001-SD-E	Flash Memory Family Software Drivers
АР-006-РТ-Е	Data Protection Method of SHARP Flash Memory
AP-007-SW-E	RP#, V _{PP} Electric Potential Switching Circuit

NOTE:

1. International customers should contact their local SHARP or distribution sales office.

A-3 STATUS REGISTER READ OPERATIONS

If AC timing for reading the status register described in specifications is not satisfied, a system processor can check the status register bit SR.15 instead of SR.7 to determine when the erase or program operation has been completed.

	NOTES:
SR.15 = WRITE STATE MACHINE STATUS: (DQ_{15}) 1 = Ready in All Partitions 0 = Busy in Any Partition	SR.15 indicates the status of WSM (Write State Machine). If SR.15="0", erase or program operation is in progress in any partition.
 SR.7 = WRITE STATE MACHINE STATUS FOR EACH PARTITION: (DQ₇) 1 = Ready in the Addressed Partition 0 = Busy in the Addressed Partition 	SR.7 indicates the status of the partition. If SR.7="0", erase or program operation is in progress in the addressed partition. Even if the SR.7 is "1", the WSM may be occupied by the other partition.

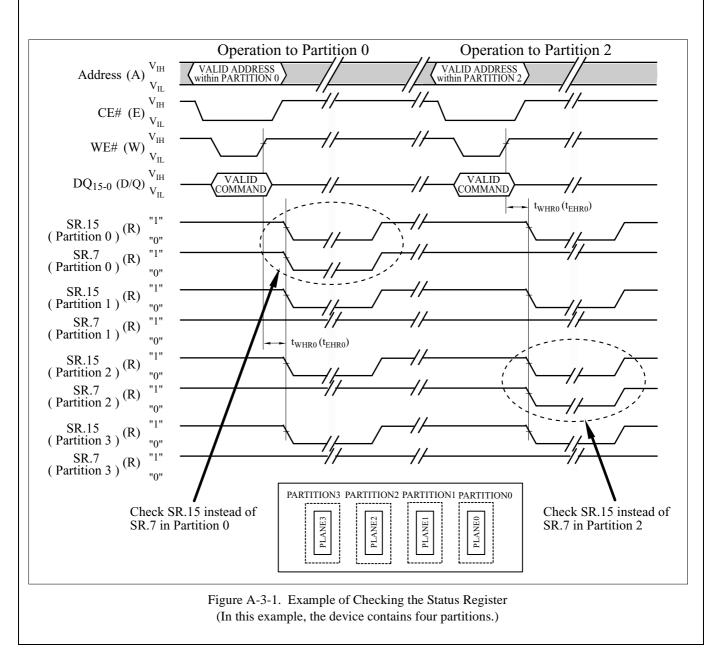


Table A-3-1. Status Register Definition (SR.15 and SR.7)

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